NMTO W annier-like functions for insulators and m etals

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M arch 23, 2024

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A bstract

W ithin this paper we outline a m ethod able to generate truly m inim al basis sets which describe either a group of bands, a band, or even just the occupied part of a band accurately. These basis sets are the so-called N M TOs, M u n T in O rbitals of order N. For an isolated set of bands, sym m etrical orthonom alization of the N M TOs yields a set of W annier functions which are atom -centered and localized by construction. They are not necessarily m axim ally localized, but m ay be transform ed into those W annier functions. For bands which overlap others, W annier-like functions can be generated. It is show n that N M TOs give a chem ical understanding of an extended system . In particular, orbitals for the and bands in an insulator, boron nitride, and a sem i-m etal, graphite, w ill be considered. In addition, we illustrate that it is possible to obtain W annier-like functions for only the occupied states in a m etallic system by generating N M TOs for cesium . Finally, we visualize the pressure-induced s ! d transition.

K eyw ords: W annier functions, density functional calculations, electronic structure, mu n-tin orbitals, solid-state

1 Introduction

The electronic structure of condensed matter is usually described in terms of one-electron basis sets. Basis functions used for computation are often simple, e.g. Gaussians or plane waves, but their number is large, 1-2 orders of magnitude larger than the number of electrons to be described. This is so because the potential in the electric one-electron Schrödinger equation, arising say in density-functional theory, is rather deep inside the atom s. The results of this kind of computation therefore require interpretation and simplication in terms of a small set of intelligible orbitals. The results of band-structure calculations for crystals, for instance, are often param etrized in terms of tight-binding models.

The C ar-P arinello technique for perform ing ab initio m olecular-dynam ics simulations using density-functional theory, pseudopotentials, plane-wave basis sets, and supercells, [1] created a need to visualize them ical bonds, and this caused renewed interest in generating localized W annier functions for the occupied bands. For a set of M isolated energy bands, "_j (k); the W annier functions, w_m (r T); enumerated by m (= 1;::;M) and by the N (! 1) lattice translations, T; is a set of orthonorm al functions which spans the eigenfunctions,

$$_{jk}$$
 (r) = N $\frac{1}{2}$ M_{m} (r T) u_{jm} exp ik T (1)
T m = 1

with eigenvalues $"_{i}$ (k); of the one-electron Schrödinger equation. The B loch

states (1) are delocalized, and the set is enum erated by the band index j and the B loch vector k: W annier functions are not unique, because performing a unitary transformation, $W_{m,m^0,T-T^0}$; of one set produces another set which also satis es Eq. (1), merely with dierent jk-dependent phases of the B loch functions. For molecules, it had long been recognized that chemical bonds should be associated with those linear combinations of the occupied molecular orbitals which are most localized, because those linear combinations are most invariant to the surroundings. [2] For in nite periodic systems, M azari and Vanderbilt have developed a useful method for projecting from the B loch states a set of so-called maxim ally localized W annier functions. [3{5]

This paper deals with a di erent kind of basis set, speci cally, minim al basis sets of localized orbitals, the new ly developed N M TOs (M u n T in O rbitals of order N, also known as 3rd generation M TOs. [6{9]) W e shalldem onstrate that with N M TOs it is possible to generate W annier functions directly, instead of via projection from the delocalized B loch states. N M TOs are constructed from the partial-wave solutions of Schrodingers equation for spherical potential wells (overlapping m u n tins) and N M TO sets are therefore selective in energy. As a consequence, one can construct an N M TO s are atom -centered and localized by construction, they do {after sym m etrical orthonorm alization{ form a set of localized W annier functions which, if needed, can be recombined locally to have m axim al localization. The N M TO technique is prim arily for generating a localized, m inim al ba-

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sis set with speci c orbital characters, and it can therefore be used also to pick a set of bands which overlap other bands outside the energy region of interest. The corresponding N M TOs {orthonorm alized or not{ we refer to as W annier-like.

N M TO-generated W annier functions have so-far been used only in a few cases to visualize them ical bonding [9,10] and m ore offen to construct H ubbard H am iltonians for strongly correlated 3d-electron system s. [10{13] In the future, it m ay be possible to use N M TO s for real-space electronic-structure m ethods in which the computational e ord increases m erely linearly with system size, so-called order-N m ethods. [14,15]

In this paper we will focus mainly on showing how NMTOs may be used to pick speci c states in insulating, sem im etallic and m etallic systems, namely boron, graphite, and cesium. Since NMTOs are unfamiliar to most readers of this issue, and more complicated than plane waves, we start out by illustrating them ain ideas by performing an elementary analytical calculation of the -bonds in the simplest tight-binding (TB) model of benzene. Then follows a concise summary of the NMTO formalism.

2 NMTO basics

2.1 Tight-binding calculation of the benzene -bond The simplest TB model for the six -electrons in benzene has six orthonorm al p_z -orbitals, $'_1$; ...; $'_6$; placed on the consecutive corners of the hexagon. The hopping integrals over the short (double) bonds are: H $_{\rm 12}$ = H $_{\rm 34}$ = H $_{\rm 56}$ =

- (1 + d) ; and those over the long (single) bonds are: H $_{\rm 61}$ = H $_{\rm 23}$ = H $_{\rm 45}$ =
- (1 d), where d is the dimerization.

In order to calculate the W annier function for the three occupied bonding states, it is convenient to partition the orbitals into those on the even (e)and those on the odd (o)-num bered sites. The eigenvalue equations are then: $H_{oo}u_{o} + H_{oe}u_{e} = "1_{oo}u_{o}$ and $H_{eo}u_{o} + H_{ee}u_{e} = "1_{ee}u_{e}$; in terms of the 3 3 blocks of the Ham iltonian and the unit matrices. Solving the last set of equations for the eigenvector for the even orbitals yields:

$$u_{e} = (\mathbf{"} \quad \mathbf{H}_{ee})^{-1} \mathbf{H}_{eo} u_{o}; \qquad (2)$$

and inserting in the rst equations results in the eigenvalue equation:

$$H_{oo} + H_{oe} ("1_{ee} H_{ee}) H_{eo} u_{o} = "1_{oo}u_{o};$$
(3)

for the (Lowdin) downfolded Ham iltonian.

In the present case where there is no hopping between even or odd sites, $H_{ee} = H_{oo} = 0:M$ oreover,

$$H_{eo} = H_{oe}^{y} = B_{e}^{y} = 0 \qquad 1$$

$$H_{eo} = H_{oe}^{y} = B_{e}^{y} = 0 \qquad (1 + d) \qquad (1 - d) E_{A}^{z};$$

$$(1 - d) = 0 \qquad (1 + d)$$

and

The latter, downfolded Ham iltonian is periodic with period 3 and is therefore diagonalized by the unitary transformation

$$U_{ok} = \begin{bmatrix} 0 & 1 \\ B & \frac{p^{1}}{3} & \frac{p^{1}}{2} & \frac{p^{1}}{6} \\ B & \frac{p^{1}}{3} & \frac{p^{1}}{2} & \frac{p^{1}}{6} \\ B & \frac{p^{1}}{3} & \frac{p^{1}}{2} & \frac{p^{1}}{6} \\ B & \frac{p^{1}}{3} & \frac{p^{2}}{6} \end{bmatrix} ;$$
(5)

yielding singly degenerate a-states (k = 0) with " = 2 and doubly degenerate e-states (k = 1) with " = $p = \frac{p}{1 + 3d^2}$: The even components of the eigenvectors are obtained from equation (2): $U_{ek} =$ " ${}^{1}H_{eo}U_{ok}$; and nally we can renorm alize: $u = U = \frac{p}{2}$:

Having found all six B loch eigenstates, we need to form three W annier functions, that is, three congruent linear combinations of the bonding states. The three downfolded p_z -orbitals, $_{o}$; de ned by: $_{o}U_{ok} = '_{o}u_{ok} + '_{e}u_{ek}$; are obviously congruent. M oreover, they are localized in the sense that $_{1}$ vanishes on the other odd sites (3 and 5). In the present case, they are also orthonorm al and, hence, W annier functions. Left-multiplication with

 $(U_{ok})^{1} = U_{ko}$ yields:

$$_{1} = \frac{1}{\frac{p}{2}} \prime_{1} + \frac{2}{3} + d \prime_{2} + \frac{2}{3} d \prime_{6} \frac{1}{3} \prime_{4} ; \qquad (6)$$

and ₃ and ₅ by cyclic permutation of site indices. Here and in the following, we work merely to rst order in the dimerization, d: The W annier function in Eq. (6) is essentially the N M TO. It is atom -centered and, as the dimerization increases, it becomes lopsided towards site 2; i.e., it spills into the short bond. It breaks the symmetry (when $d \in 0$) because it was chosen to vanish on the odd sites dierent from its own, and it is not maximally localized (unless d =0). Nevertheless, it is a fairly simple matter to achieve maximal localization and, hence, to restore the symmetry, by noting a unitary transformation, $W_{T T^0}$; which maximizes e.g. $jw \int_{T}^{0} \frac{P_{0}}{R=1} jw \int_{T}^{0}$: Here, $w_1 = \frac{P_{0}}{T} W_{1 T T}$ is the maximally localized W annier function. In the present case, W has only one independent matrix element and we nd:

$$w_{1} = \frac{1}{3^{\frac{p}{2}}} \begin{pmatrix} p_{-\frac{q}{3}+1} + \frac{p_{-\frac{q}{3}}}{2} d & ('_{1}+'_{2}) + 1 & \frac{p_{-\frac{q}{3}}}{3} d & ('_{3}+'_{6}) \\ p_{-\frac{q}{3}-1} & \frac{p_{-\frac{q}{3}}}{2} d & ('_{4}+'_{5}) & ; \quad (7) \end{pmatrix}$$

which is clearly symmetric (bond-centered). From (6): $j \int_{-1}^{4} = \frac{19}{54} + 0$ (d²); and from (7): $jw \int_{-1}^{4} = \frac{19}{54} + \frac{2^{p} \overline{3}}{9} d + 0$ (d³): Hence, for d = 0; the atom -centered and the bond-centered W annier functions are both maximally localized and symmetric. Now, the NMTO set, ${}_{0}^{(N)}$; is obtained without solving the eigenvalue equations, i.e., is not obtained by projection from the Bloch states through multiplication by $(U_{ko})^{-1}$; but in a more tricky way: W e ist de ne a set of downfolded, energy-dependent orbitals,

$$\circ (") \quad \prime_{\circ} 1_{\circ\circ} + \prime_{e} ("1_{ee} \quad H_{ee})^{\perp} H_{e\circ};$$
 (8)

which are localized when " does not coincide with an eigenvalue of H_{ee} : D EProjection onto the even sites yields: '_e \hat{H} " _o (") = 0_{oo}; so we realize that the functions of the set _o (") are solutions of the in purity problem s specified by the boundary conditions that _o (") vanishes at the other odd sites and is normalized to ' at its own site. Projection onto the odd sites yields:

$$\overset{D}{}_{\circ} \overset{E}{H} \overset{E}{}_{\circ} (") \overset{E}{=} H_{\circ\circ} + H_{\circe} ("1_{ee} H_{ee})^{-1} H_{e\circ} "1_{\circ\circ} G_{\circ\circ} (")^{-1};$$
(9)

and comparison with (3) shows that, if " is an eigenvalue of the (downfolded) H am iltonian and u_o an eigenvector, then $_o$ (") u_o is an eigenfunction. G (") de ned in (9) is the resolvent. Finally, we need to nd an energy-independent, N th-order approximation to the set $_o$ ("): W e form the set, $_o$ (") G_{oo} ("); of (contracted G reens) functions and add an analytical function of energy determined in such a way that the two sets of functions, $_o$ (") G_{oo} (") and $_o^{(N)}G_{oo}$ ("); coincide when " is on an energy mesh, $_0$; ..., specifying the energy range of interest. By taking the highest-order nite di erence on this mesh, one obtains:

$${}^{(N)}_{\circ} \frac{{}^{N} G_{\circ\circ}}{[0:::N]} = \frac{{}^{N} {}_{\circ} G_{\circ\circ}}{[0:::N]};$$
(10)

which determ ines the set of (non-orthonorm al) NMTOs. For N = 1; for instance:

$${}^{(1)}_{\circ} = \left[{}_{\circ} \left({}_{1} \right) G_{\circ\circ} \left({}_{1} \right) \right]_{\circ} \left({}_{0} \right) G_{\circ\circ} \left({}_{0} \right) \left[G_{\circ\circ} \left({}_{1} \right) \right]_{\circ} G_{\circ\circ} \left({}_{0} \right) \left[{}^{1}_{\circ} \right]_{\circ} \left({}^{1}_{\circ} \right) \left[G_{\circ\circ} \left({}^{1}_{\circ} \right) \right]_{\circ} \left[G_{\circ\circ} \left(G_{\circ\circ} \left({}^{1}_{\circ} \right) \right]_{\circ} \left[G_{\circ\circ} \left(G_{\circ\circ} \left(G_{\circ\circ} \right) \right]_{\circ} \left[G_{\circ\circ} \left(G_{\circ\circ} \left(G_{\circ\circ} \right) \right]_{\circ} \left[G_{\circ\circ} \left(G_{\circ\circ} \left(G_{\circ\circ} \left(G_{\circ\circ} \right) \right]_{\circ} \left[G_{\circ\circ} \left(G_{\circ\circ} \left(G_{\circ\circ} \left(G_{\circ\circ} \right) \right]_{\circ} \left[G_{\circ\circ} \left(G_{\circ\circ} \left(G_{\circ\circ} \left(G_{\circ\circ} \right) \right]_{\circ} \left[G_{\circ\circ} \left(G_{\circ\circ}$$

For the sim ple benzene m odel, Eq. (8) yields:

$$_{1}$$
 (") = $'_{1}$ $\frac{1+d}{m}'_{2}$ $\frac{1-d}{m}'_{6};$

and $_3$ (") and $_5$ (") by cyclic permutation of site indices. To order d; the downfolded Ham iltonian (4) is independent of d; and by subtracting " and inverting, we nd:

$$G_{\infty} (") = \frac{"}{("^{2} \ 1) ("^{2} \ 4)} \begin{bmatrix} 0 & 1 \\ 1 & 2 \end{bmatrix} \begin{bmatrix} 1 & 1 \\ 2 & 1 \end{bmatrix} \begin{bmatrix} 1 & 2 \\ 2 & 2 \end{bmatrix} \begin{bmatrix} 1 & 2 & 2 \\ 2 & 2 \end{bmatrix} \begin{bmatrix} 1 & 2 & 2 \\ 2 &$$

Specializing to N = 1; the LM TO found from (11) is:

and if, with the bene t of hindsight, we choose $_{0} = 2$ and $_{1} = 1$; we obtain the exact result (6), apart from the normalization, $1/\overset{\text{p}}{2}$. With other choices, the LM TO set is an approximation to the exact Hilbert space spanned by $_{0}$ or w₀; as explained in connection with Eq. (13) below. We have it to the reader to convince him self that had we chosen $_{0} = 2$ and $_{1} = 1$; we would have obtained the W annier functions for the antibonding levels.

By considering a simple TB model, we have thus learned that the NM TO procedure for constructing a minim albasis set, speci cally a set of localized W annier functions, consists of the following steps: 1) D ownfolding to a small set of energy-dependent orbitals and 2) a polynomial approximation of the latter. The resulting NM TO set is not orthonormal in general, but may be symmetrically (Lowdin) orthonormalized in a third step. W annier functions which are maximally localized, and therefore not symmetry breaking, may be obtained in a fourth step. N one of these steps require know ledge of the extended (B loch) eigenstates. A lthough of utmost importance for applications, steps (3) and (4) are not speci c for the NM TO method and fairly standard. A s a consequence, they will not be considered further in this paper.

2.2 NMTOs for real system s

For real systems, the NMTO method constructs a set of atom-centered local-orbital basis functions which span the solutions of the one-electron Schrodinger equation for a local potential, written as a superposition,

 $_{R}$ v_R (jr R), of spherically symmetric, short-ranged potential wells, a so-called overlapping mun-tin potential. This is done by rst solving the radial Schrödinger (or D irac) equations numerically to nd ' $_{R1}$ ("; jr R) for all angular momenta, 1; with non-vanishing phase-shifts, for all potential wells, R; and for the chosen set of energies, " = $_{0}$; :::; N.

The partial-wave channels, $R \ln i$; are partitioned into active (odd, in the benzene example) and passive (even). The active ones are those for which one wants to have orbitals in the basis set. E.g. for the red -bands in Figure 1 the active channels are p_z on all the carbon atom s, whereas for the black bands, the active channels include all nine s; p; and d-channels on all the carbon atom s.

For each active channel, $R \ln i$, a kinked partial wave, $R \ln (";r)$ (Eq. (8) in TB theory), is now constructed from all the partial waves,

 $'_{R1}$ ("; \dot{r}_{R1}) $Y_{Im} \rightarrow R$, inside the potential-spheres, and from one solution, $_{RIm}$ ("; r); of the wave-equation in the interstitial, a so-called screened spherical wave. The construction is such that the kinked partial wave is a solution of Schrodinger's equation at energy " in all space, except at som e hard screening-spheres {which are concentric with the potential-spheres, but have no overlap { where it is allowed to have radial kinks in the active channels.

In passive channels, the matching is smooth.

It is now clear that if we can form a linear combination of such kinked partial waves with the property that all kinks cancel, we have found a solution of Schrödinger's equation with energy ": In fact, this kink-cancellation condition (Eq.s (9) and (3) in TB theory) leads to the classical method of K orringa, K ohn, and R ostoker [16] (K K R), but in a screened representation and valid for overlapping M T potentials to leading order in the potential overlap.

W hereas the screened spherical wave must join smoothly onto all passive partial waves, we can require that it vanishes at the hard spheres for all the active channels except the eigenchannel. This con nem ent is what makes the screened spherical wave localized, provided that localized solutions exist for the actual potential, energy, hard spheres, and chosen partition into active and passive channels. Since the screened spherical wave is required to vanish merely in the other active channels, but not in the eigenchannel, it is an impurity solution for the hard-sphere solid and is given by Eq. (8) in TB theory.

Finally, the set of N M TOs is formed as a superposition of the kinkedpartial-wave sets for the energies, $_1$;; N :

$$\sum_{\substack{(N) \\ R \ lm}}^{(N)} (r) = \sum_{\substack{n = 0 \\ R \ lm}}^{N} (n; r) L_{n; R \ lm}^{(N)} :$$
 (12)

Note that the size of this NMTO basis set is given by the number of active

channels and is independent of the number, N + 1; of energy points. The ∞ e cient m atrices, L $_{n}^{(N)}$; in equation (12) are determined by the condition that the set of N M TOs span the solutions, _ i ("_i;r); of Schrödinger's equation with an error

$$\sum_{i}^{(N)} (\mathbf{r}) = c^{(N)} (\mathbf{u}_{i} = 0) (\mathbf{u}_{i} = 1) ::: (\mathbf{u}_{i} = N)$$

$$+ o ((\mathbf{u}_{i} = 0) (\mathbf{u}_{i} = 1) ::: (\mathbf{u}_{i} = N)) :$$

$$(13)$$

This condition leads to Eq. (10) and the N M TO set is a polynom ial approximation for the H ilbert space of Schrödinger solutions, with $L_n^{(N)}$ being the coecients in the corresponding Lagrange interpolation formula. Expression (11) is for N = 1. An N M TO with N = 0 is a kinked partial wave, but an N M TO with N > 0 has no kinks, but merely discontinuities in the $(2N + 1)^{st}$ radial derivatives at the hard spheres for the active channels. The prefactor, $c^{(N)}$; in expression (13) is related to this, [6] and it decreases with the size of the set, i.e. with the number of active channels.

A basis set which contains as many orbitals as there are bands to be described, we shall call truly minimal. For an isolated set of bands, the truly minimal N M TO basis converges to the exact H ilbert space as the energy mesh which spans the range of the bands becomes ner and ner. Symmetrical orthonormalization of the converged N M TO set therefore yields a set of atom-centered W annier functions which are localized by construction. The localization depends on the system and on the choice of downfolding. Had we, for instance for benzene, chosen instead of the odd sites, sites 1, 2 and 3 as active, the corresponding N M TO W annier functions would have been less localized, the H ilbert space spanned by them would have needed a larger N for convergence, and the construction from this set of the m axim ally localized W annier functions would have required a larger cluster. N evertheless, the calculation could have been done. Sim ilarly, in real systems the choice of active channels and their hard-sphere radii {their num ber and m ain characters being xed by the nature of the band to be described{ in uences the properties of the individual N M TO s, but not the H ilbert space they converge to.

3 Results and Discussion

3.1 Graphite: a sem i-m etal

The bonding in graphite is understood: within a single graphene sheet the s, p_x and p_y orbitals on the two carbon atom s per primitive cell hybridize to form a set of sp^2 -bonding bands which are occupied, and a set of - antibonding bands which are empty. There are two sheets per cell.

The p_z orbitals form a group of bonding and antibonding -bands which just touch at the Ferm i-level, making graphite a sem imetal. In order to describe the set of -bands, we would need to construct two equivalent N M TOs per sheet, each centered on a single carbon atom . We have it to the method to shape the orbitals, subject to the aforem entioned boundary conditions for the screened spherical waves. The energy mesh must be chosen in such a way so that it spans the energy range of the -bands and excludes the energy range where the bands hybridize with other bands.

In Figure 1 the band structure of graphite calculated with a full spd basis set on each carbon atom is given in black. It is in excellent agreement with previous calculations. [17] The red bands have been calculated with a basis set comprised of one p_z Quadratic-M TO, or QM TO (N = 2). The energy meshes used for both calculations are given to the right of the band structures. The two sets of bands are almost identical, on the scale of the gure, with the exception of a sm allbum p at the top of the red bands, where hybridization with other bands occurs. Thus, it is possible to describe the set of occupied and unoccupied -bands in graphite via just one orbital on every carbon atom, shown to the right of the band structure. The orbital is localized because it is not allowed to have any p_z character on any of the other carbons. It is allowed to have other orbital characters, (E.g. s; p_x ; d_{xy}), on the other symmetry-equivalent carbons, but such characters are not visible in the gure.

It is even possible to generate orbitals for just the occupied or unoccupied bands in graphite. In this case we only want to pick half of the bands, and therefore we need a basis with, say, a p_z orbital on every second carbon atom with all other partial waves being downfolded, i.e. passive. Moreover, an energy mesh spanning the bonding (anti-bonding) bands must be used in order to obtain the bonding (anti-bonding) orbital for graphite. Thus, the

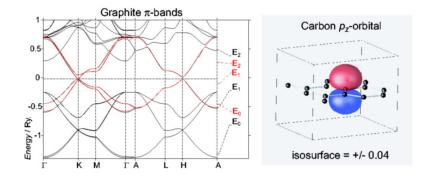


Figure 1: The band structure of graphite calculated with a full spd basis is given in black. The red bands have been calculated with a p_z QMTO (shown on the right) on every carbon atom. The energy meshes used for each calculation are given to the right of the band structure. In all gures, red denotes a positive and blue a negative isosurface value. For the orbital plots, the isosurface values are given in units of $a_B^{3=2}$, where a_B is the Bohr radius.

choice of the energy mesh determ ines which set, bonding or anti-bonding, is chosen. In Figures 2 and 3 the orbital on the central carbon atom is shown, along with the band structures computed with a full spd basis (in black) and those with the truly-minimal basis set we have just specified (in red). The agreement between the two sets of bands is excellent, with only minor deviations in the upper regions of the downfolded band structure of the anti-bonding bands where hybridization with the next higher bands occurs. Inspection of the -bonding and anti-bonding orbitals shows that they spread out onto the rst nearest-neighbour carbon atoms (passive), but they are con ned not to have any p_z character on those carbon atoms, e.g. the second

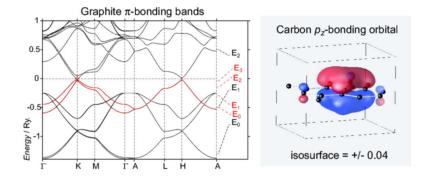


Figure 2: As in the previous gure, but the red bands have now been calculated with a p_z Cubic-M TO (shown on the right) on every second atom within a single graphene sheet. The energy mesh is chosen within the occupied part of the -band, which is therefore selected.

nearest neighbours, where the basis set has orbitals (active partial waves). The third nearest neighbour atom s also have all partial waves downfolded and som e p_z character m ay be seen. C learly, this choice of orbitals breaks the sym m etry; the sam e H ilbert space would have been obtained had the orbitals been placed on the other half of the carbon atom s.

It is also possible to describe the sp^2 -bonding bands in graphite by placing an s, p_x and p_y orbital on every second carbon atom, downfolding all other channels and using an energy mesh which spans the energy range of the bands of interest. The band structure obtained with this basis is given in red in Figure 4 and is identical, on the scale of the gure, to the black bands which have been calculated using a full spd basis set on every carbon atom. The orbitals may spread out onto the nearest neighbour carbons, how ever

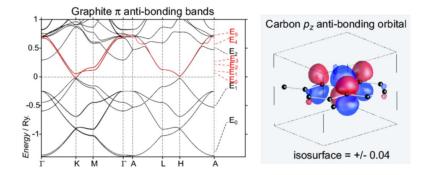


Figure 3: As in the previous gure, but the energy mesh is now in the empty part of the -band.

are con ned not to have any s, p_x or p_y character on the second nearest neighbours. Sym m etrical orthonorm alization of these three orbitals gives the well known bond orbital, the carbon sp^2 N M TO, also shown in the gure.

The above examples show that it is possible to describe a chosen band, or set of bands, with a truly minimal basis set consisting of one NMTO per band. Moreover, the NMTOs obtained from our method are in-line with an intuitive chemical picture of bonding in the solid state, except that they may break the symmetry. This arbitrariness originating in the constraint that the NMTOs be atom -centered can be removed by forming linear combinations of maximally localized W annier functions. Hence, NMTOs should be useful not only, for example, as basis sets in linear scaling methods, but also in gaining a chemical understanding of periodic systems.

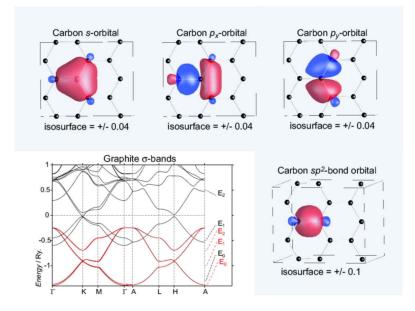


Figure 4: As in the previous gures, but the red bands have now been calculated with an s;p_x and p_y QMTO on every second carbon atom (shown above the band structure). Also shown is one of the three congruent sp²-bond orbitals which arise by symmetrical orthonorm alization of the s;p_x and p_y orbitals.

3.2 Boron N itride: an insulator

The bonding in boron nitride is similar to that in graphite: within a single layer the s, p_x and p_y boron and nitrogen orbitals hybridize to form sp^2 -bonding and -antibonding bands. The alternation, however, makes the

system insulating with a band gap between the bonding and anti-bonding

-bands. In order to describe the occupied bands, it is possible to generate either boron or nitrogen centered NMTOs. It can be expected that the electron density, and hence the orbital at a given isosurface, should have a maximum closer to the more electronegative element, nitrogen. The method needs to do less 'work' if the orbitals are placed initially where the electrons are thought to be. Thus, we rst place all the orbitals on nitrogen, and let the method shape them accordingly. This choice of atom -centered orbitals corresponds to the extrem e ionic limit, a $B^{3+}N^{3}$ con guration. The bonding

and -bands and their respective N M TO s are shown in the top and bottom part of F igure 5, respectively. The s; p_x and p_y N M TO s are not shown, since they are very similar to those obtained for graphite. The full band structure is in excellent agreement with previous calculations. [18]

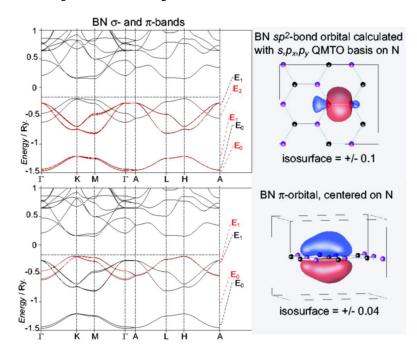


Figure 5: The band structure of boron nitride calculated with a full spd basis is given in black. The red -bonding bands in the upper panel have been calculated with an s; p_x and p_y QM TO on all nitrogen atom s, and the red -bonding bands in the bottom panel with a p_z orbital on all nitrogen atom s. A lso given is one of the three equivalent sp²-bond orbitals and the p_z LM TO. Boron atom s are purple, nitrogen black.

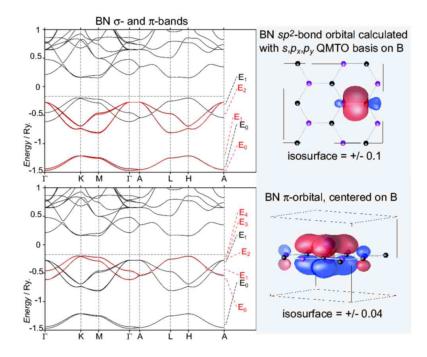


Figure 6: As in the previous gure, but with boron-centered and basis sets.

In new materials where the bonding is not well understood, it may be di cult to decide where the orbitals should be placed. In the following we will show that N M TO s are forgiving: even a bad starting guess can yield the correct bands and H ilbert space. P lacing all the orbitals on the boron atom s (a B⁵ N⁵⁺ con guration) yields the bands and orbitals shown in Figure 6. The sp²-bond orbital boks identical to the one shown in Figure 5, as it should be when the energy mesh is converged. For the -bands, more energy points are necessary since the orbital has to spread out from a central boron onto three neighboring nitrogens. Inspection of the boron (nitrogen) centered – N M TO s makes it plausible that when squared and summed over all boron (nitrogen) sites, they give the same electron density, with maxima shifted towards nitrogen.

3.3 Cesium : a m etal

W ithin this section we will demonstrate that it is even possible to generate W annier-like functions that span only the occupied bands of a metal. For lack of space, we must have it to the reader to generalize our TB model for benzene to the corresponding model for the in nite, slightly dimerized chain, and then to study what happens for vanishing dimerization.

We shall rst bok at the convergence of the orbital with respect to the size of the supercell used. W hereas we can only hope to reproduce the long-ranged Friedel oscillations for supercells so large that the facets of the foldedin B rillouin zone resemble those of the Ferm i surface, much smaller cells turn out to reproduce the rough shape of the occupied orbital. This is a manifestation of what W alter K ohn named the "nearsightedness" of the electronic structure of matter. [19] W e shall speci cally consider cesium because of the interesting chemical aspect that its s-electron transforms into a d-electron under hydrostatic pressure.

The band structure of cesium at am bient conditions (C s-I) calculated with a full sd basis set on every atom is given in Figure 7 in black. Superim – posed on it in red is the band calculated with one s orbital on every second cesium atom, obtained speci cally by breaking the symmetry and treating C s m etal as C sC l-structured C s⁺ C s : In most regions of the B rillouin zone

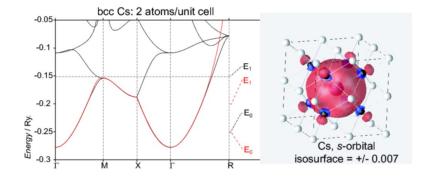


Figure 7: Band structure of bcc cesium folded into the 2 atom /cell (C sC l) simple cubic Brillouin zone. The black bands were calculated with a basis containing the s and d LM TO s on all atom s. The red bands were calculated with an s LM TO on every second cesium atom, which is also shown. The white atom s have an s orbital placed on them (active), whereas on the black atom s all partial waves are downfolded (passive).

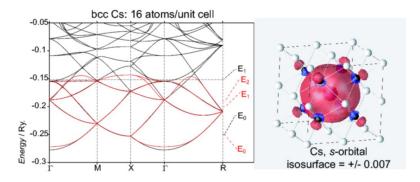


Figure 8: As in the previous gure, but for a 16-atom supercell.

the agreem ent between the two is good, except it is obvious that with this supercell it is not possible to describe the occupied part of the upper band along the X-line. Nonetheless, the orbital can be plotted and is shown in Figure 7.

The result obtained by doubling the cell in all three directions is shown in

Figure 8. Now the occupied band structure has in proved considerably, but is not yet perfect. The body of the orbital obtained from this calculation is, however, very similar to the one generated from the C sC l supercell. The longranged tailwe do not monitor with the contour chosen in the gures. A lready, this orbital at low isosurfaces shows the onset of sd-hybridization. At high isosurfaces (not shown), the orbital is completely s-like. The hybridization is evident in the d_{z^2} character found on the nearest-neighbour atom swhich have all partial waves downfolded, and therefore can posses any orbital character. It is a result of the fact that even though the occupied band has primarily s character, near the Ferm i level some regions with t_{2g} and d_{z^2} character can be found.

Under pressure, œsium undergoes a variety of interesting structural phase transitions. At 2.3 GPa Cs-I (box œsium) transforms to an fix phase. [20] Until recently, it was believed that Cs-II undergoes an isostructural transition to Cs-III (which is found in a very narrow pressure range between 4.2 and 4.3 GPa). However, experiments have shown that Cs-III has a very complicated structure which is orthorhom bic (space group C 222₁ with 84 atom s per unit cell). [21] At 4.3GPa Cs-III transforms to the non-closepacked tetragonal Cs-IV [22] which at 12GPa undergoes a transition to orthorhom bic Cs-V [23] and nally to the double hexagonal close packed C s-VI at 70GPa. [24] These structural transitions are beleived to be driven by the pressure-induced s ! d valence electron transition. [25] Here we will generate N M TOs for Cs-II and Cs-IV in order to visualize how the valence

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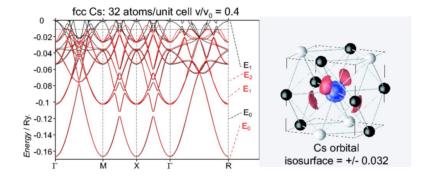


Figure 9: As in the previous gure, but for fcc cesium with $v=v_0 = 0.4$, and a 32-atom supercell.

s orbital in cesium changes with increased pressure.

The occupied bands for $C s - \Pi w$ ith $v = v_0 = 0.6$ are still primarily s-like, however a fair amount of e_g -character can also be found. Upon increasing pressure, a Lifshitz transition occurs (change in the topology of the Ferm i surface) as higher lying t_{2g} bands cross the Ferm i level. Figure 9 shows the band structure of $C s - \Pi$ for a 32-atom supercell compressed past the calculated volume of the Lifshitz transition. The agreement between the downfolded and full band structures is excellent and the downfolded bands are even able to describe the aforementioned t_{2g} bands. The orbital at high isosurfaces is clearly no longer s-like. It must be noted that the orbital calculated for $v=v_0 = 0.6$, using the same supercell and downfolding scheme, yielded a very similar orbital (not shown), the only difference being that the four lobes evident in Figure 9 are located in the same plane. C s-IV with each cesium atom having a coordination of 8 is no longer a close-packed structure. It can be viewed as a stacking of prisms with a ninety degree rotation from layer to layer in the c-direction. The TB-LM TO calculated charge density (Figure 10) show sm axim a in the interstitial regions, in the center of these prisms. The LM TO obtained by placing one sorbital on every second cesium atom and downfolding all other partial waves is given in Figure 10. C learly this orbital can be obtained from that shown in Figure 9 by raising two and lowering two of the lobes. P lacing the C s-IV LM TO on all of the active sites and squaring it yields a charge density which is alm ost identical to that calculated with TB-LM TO, [26] giving further validation that our m ethod works. Thus we have shown that N M TO sm ay be used to give a chemical picture of the pressure induced electronic phase transition in cesium yielding results which are in-line with those obtained from standard electronic structure calculations.

4 Summary and conclusions

W ithin this article we have shown that the 3rd generation M TO m ethod can be used to design a basis set of atom -centered localized orbitals, which span the wave functions in a given energy range. For an isolated set of bands, arbitrary accuracy m ay be obtained, with only one basis function per electron pair (or single electron, in the case of spin-polarized calculations), sim ply by increasing the density of the energy m esh which spans the energy range of the band in question. This method may be applied to insulating and even metallic systems to generate W annier-like functions which are in-line with a chem ical understanding of bonding in the solid-state. It should therefore be a useful analysis tool in, for example, explaining experimental trends for a given set of compounds via orbital based arguments; clarifying the bonding in novel or even am orphous materials; visualizing pressure-driven electronic transitions.

3rd generation M TO sm ay also be useful in generating truly-m in im al basis sets for order-N m ethods and in constructing m any-electron wave functions which can be applied to study strongly correlated system s realistically. In our im plem entation, N M TO s are generated using the self-consistent potential

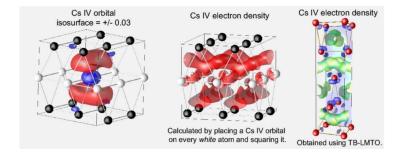


Figure 10: The LM TO obtained for Cs-IV (v=v₀ = 0.316) with 2-atom s/cell. An sorbital was placed on all white atom s (active), whereas the partial waves on the black atom s were downfolded (passive). Also shown is the charge density obtained by placing the LM TO on every white atom and squaring it, along with the charge density obtained from a TB-LM TO calculation. The latter charge density is colored by the ELF. The isosurface taken is 0.0063 a_B^{3} .

from an LM TO calculation. However, ourm ethod m ay be interfaced with the results of any other program, providing that the potential can be expressed in terms of a superposition of spherically symmetric potential wells with radial overlaps of up to 60 percent.

5 ComputationalM ethods

G raphite has a hexagonal unit cell. The space group is P_{0_3}/mmc (194) and the two basis carbon atom s are located in the 2b and 2c W ycko positions. The lattice constants, a and c were taken from experimental data [27] as being 2.4642 A and 6.7114 A, respectively. In addition to the atom s on the two crystallographic positions, it was necessary to insert two interstitial spheres to represent the charge density in the calculation.

Boron nitride is also found with space group P_{6_3}/mmc (194), with the boron atom located in the 2c and the nitrogen atom in the 2d W yko positions. The lattice constants, a and c were taken from experimental data [28] as being 2.50399 A and 6.6612 A, respectively. It was only necessary to insert one interstitial sphere.

At am bient conditions, cesium crystalizes in the bcc structure. Calculations were performed using the experimental lattice parameter of 6.048 A. [29] C s-II is fcc and the bands shown here were calculated for $v=v_0 = 0.4$. Both C s-I and C s-II are close-packed so it was not necessary to insert any empty spheres. C s-IV has the space group I4₁/am d with 2 atom s per unit cell [22] and it was necessary to insert four empty spheres.

All of the TB-LM TO calculations [26] were performed using the Vosko-W ilk-Nusair (VW N) LDA [30] along with the Perdew-W ang GGA. [31] Scalar relativistic e ects were included. For graphite and boron nitride a basis set consisting of spd LM TOs on the carbon, boron and nitrogen atom s with sp LM TOs on the empty spheres, was used. For cesium, the basis consisted of sd LM TOs with pf LM TOs being downfolded. For graphite and boron nitride, the calculations utilized 1953 irreducible points in the tetrahedron k-space integrations, [32] 1661 and 897 points were used in the calculation for cesium in the bcc and fcc structures (one atom per unit cell), respectively, and 693 points were used in the calculation for C s-IV.

The present version of the NMTO program is not self-consistent and requires the output of the self-consistent potential from the TB-LMTO program. The downfolded band structures are compared with bands computed employing a full NMTO basis set; not with those obtained using the TB-LMTO program. In all cases, the default values for the hard-sphere radii, a_R , were used. Thus, all of the hard spheres were slightly sm aller than touching. However in general, the a_R should be taken as 0.9 times the tabulated covalent, atom ic or ionic radii. In the calculations all partial-waves on the empty spheres were downfolded. The other downfolding schemes and energy meshes employed for particular calculations are given in the results and discussion section of the paper. Note that a mesh employing two (N + 1= 2) energy points yields a linear MTO or LMTO, one with three points a quadratic-

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M TO or QM TO, and so on. M ore details about the N M TO form alism can be found in [7{9] and references within.

A cknow ledgm ents

E Z.acknowledges nancial support from the \International M ax-P lanck Research School for A dvanced M aterials" (IM PRS-AM).

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